



Features

- 2A Peak Source/Sink Drive Current
- Wide Operating Voltage Range: 4.5V to 35V
- -40°C to +125°C Extended Operating Temperature Range
- Logic Input Withstands Negative Swing of up to 5V
- Outputs May be Connected in Parallel for Higher Drive Current
- Matched Rise and Fall Times
- Low Propagation Delay Time
- Low 10 μ A Supply Current
- Low Output Impedance

Applications

- Efficient Power MOSFET and IGBT Switching
- Switch Mode Power Supplies
- Motor Controls
- DC to DC Converters
- Class-D Switching Amplifiers
- Pulse Transformer Driver



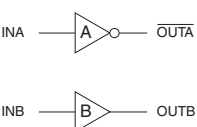
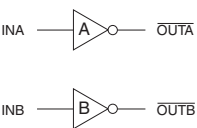
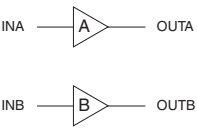
Description

The IXDF602/IXDI602/IXDN602 dual high-speed gate drivers are especially well suited for driving the latest IXYS MOSFETs and IGBTs. Each of the two outputs can source and sink 2A of peak current while producing voltage rise and fall times of less than 10ns. The input of each driver is CMOS compatible, and is virtually immune to latch up. Proprietary circuitry eliminates cross conduction and current “shoot-through.” Low propagation delay and fast, matched rise and fall times make the IXD_602 family ideal for high-frequency and high-power applications.

The IXDN602 is configured as a dual non-inverting driver, the IXDI602 is configured as a dual inverting driver, and the IXDF602 has one inverting and one non-inverting driver.

The IXD_602 family is available in a standard 8-pin DIP (PI), an 8-pin SOIC (SIA), an 8-pin Power SOIC with an exposed metal back (SI), and an 8-pin DFN (D2) package.

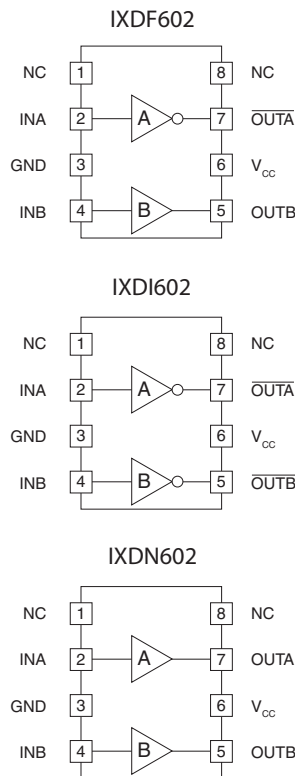
Ordering Information

Part Number	Logic Configuration	Package Type	Packing Method	Quantity
IXDF602D2TR		8-Pin DFN	Tape & Reel	2000
IXDF602PI		8-Pin DIP	Tube	50
IXDF602SI		8-Pin Power SOIC with Exposed Metal Back	Tube	100
IXDF602SITR		8-Pin Power SOIC with Exposed Metal Back	Tape & Reel	2000
IXDF602SIA		8-Pin SOIC	Tube	100
IXDF602SIATR		8-Pin SOIC	Tape & Reel	2000
IXDI602D2TR		8-Pin DFN	Tape & Reel	2000
IXDI602PI		8-Pin DIP	Tube	50
IXDI602SI		8-Pin Power SOIC with Exposed Metal Back	Tube	100
IXDI602SITR		8-Pin Power SOIC with Exposed Metal Back	Tape & Reel	2000
IXDI602SIA		8-Pin SOIC	Tube	100
IXDI602SIATR		8-Pin SOIC	Tape & Reel	2000
IXDN602D2TR		8-Pin DFN	Tape & Reel	2000
IXDN602PI		8-Pin DIP	Tube	50
IXDN602SI		8-Pin Power SOIC with Exposed Metal Back	Tube	100
IXDN602SITR		8-Pin Power SOIC with Exposed Metal Back	Tape & Reel	2000
IXDN602SIA		8-Pin SOIC	Tube	100
IXDN602SIATR		8-Pin SOIC	Tape & Reel	2000

1. Specifications	3
1.1 Pin Configurations	3
1.2 Pin Definitions	3
1.3 Absolute Maximum Ratings	3
1.4 Recommended Operating Conditions	3
1.5 Electrical Characteristics: $T_A = 25^\circ\text{C}$	4
1.6 Electrical Characteristics: $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	4
1.7 Thermal Characteristics	5
2. IXD_602 Performance	5
2.1 Timing Diagrams	5
2.2 Characteristics Test Diagram	5
3. Block Diagrams & Truth Tables	6
3.1 IXDI602	6
3.2 IXDF602	6
3.3 IXDN602	6
4. Typical Performance Characteristics	7
5. Manufacturing Information	10
5.1 Moisture Sensitivity	10
5.2 ESD Sensitivity	10
5.3 Soldering Profile	10
5.4 Mechanical Dimensions	11

1 Specifications

1.1 Pin Configurations



1.2 Pin Definitions

Pin Name	Description
INA	Channel A Logic Input
INB	Channel B Logic Input
OUTA OUTA	Channel A Output - Sources or sinks current to turn-on or turn-off a discrete MOSFET or IGBT
OUTB OUTB	Channel B Output - Sources or sinks current to turn on or turn off a discrete MOSFET or IGBT
V _{CC}	Supply Voltage - Provides power to the device
GND	Ground - Common ground reference for the device

1.3 Absolute Maximum Ratings

Parameter	Symbol	Minimum	Maximum	Units
Supply Voltage	V _{CC}	-0.3	40	V
Input Voltage	V _{IN}	-5.0	V _{CC} +0.3	V
Output Current	I _{OUT}	-	±2	A
Junction Temperature	T _J	-55	+150	°C
Storage Temperature	T _{STG}	-65	+150	°C

Unless otherwise specified, absolute maximum electrical ratings are at 25°C

Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

1.4 Recommended Operating Conditions

Parameter	Symbol	Range	Units
Supply Voltage	V _{CC}	4.5 to 35	V
Operating Temperature Range	T _A	-40 to +125	°C

1.5 Electrical Characteristics: $T_A = 25^\circ\text{C}$

 Test Conditions: $4.5\text{V} \leq V_{CC} \leq 35\text{V}$, one channel (unless otherwise noted).

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Input Voltage, High	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IH}	3.0	-	-	V
Input Voltage, Low	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IL}	-	-	0.8	
Input Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	I_{IN}	-	-	± 10	μA
Output Voltage, High	-	V_{OH}	$V_{CC}-0.025$	-	-	V
Output Voltage, Low	-	V_{OL}	-	-	0.025	
Output Resistance, High State	$V_{CC}=18\text{V}, I_{OUT}=-10\text{mA}$	R_{OH}	-	2.5	4	Ω
Output Resistance, Low State	$V_{CC}=18\text{V}, I_{OUT}=10\text{mA}$	R_{OL}	-	1.5	3	
Output Current, Continuous	Limited by package power dissipation	I_{DC}	-	-	± 1	A
Rise Time	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_r	-	7.5	15	ns
Fall Time	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_f	-	6.5	15	
On-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_{ondly}	-	35	60	
Off-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_{offdly}	-	38	60	
Power Supply Current	$V_{CC}=18\text{V}, V_{IN}=3.5\text{V}$	I_{CC}	-	1	3	mA
	$V_{CC}=18\text{V}, V_{IN}=0\text{V}$		-	<1	10	
	$V_{CC}=18\text{V}, V_{IN}=V_{CC}$		-	<1	10	μA

1.6 Electrical Characteristics: $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$

 Test Conditions: $4.5\text{V} \leq V_{CC} \leq 35\text{V}$, one channel (unless otherwise noted).

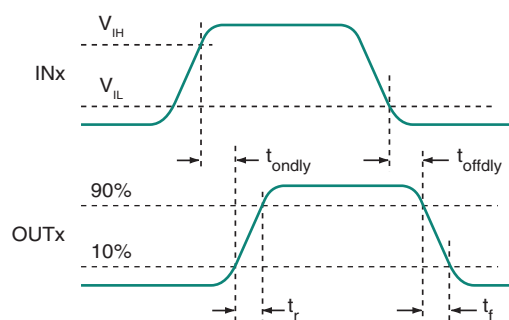
Parameter	Conditions	Symbol	Minimum	Maximum	Units
Input Voltage, High	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IH}	3.3	-	V
Input Voltage, Low	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IL}	-	0.65	
Input Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	I_{IN}	-10	10	μA
Output Voltage, High	-	V_{OH}	$V_{CC}-0.025$	-	V
Output Voltage, Low	-	V_{OL}	-	0.025	
Output Resistance, High State	$V_{CC}=18\text{V}, I_{OUT}=-10\text{mA}$	R_{OH}	-	6	Ω
Output Resistance, Low State	$V_{CC}=18\text{V}, I_{OUT}=10\text{mA}$	R_{OL}	-	5	
Output Current, Continuous	Limited by package power dissipation	I_{DC}	-	± 1	A
Rise Time	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_r	-	18	ns
Fall Time	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_f	-	18	
On-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_{ondly}	-	75	
Off-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=1000\text{pF}$	t_{offdly}	-	75	
Power Supply Current	$V_{CC}=18\text{V}, V_{IN}=3.5\text{V}$	I_{CC}	-	3.5	mA
	$V_{CC}=18\text{V}, V_{IN}=0\text{V}$		-	150	
	$V_{CC}=18\text{V}, V_{IN}=V_{CC}$		-	150	μA

1.7 Thermal Characteristics

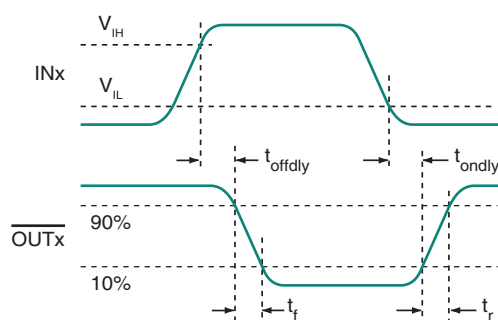
Package	Parameter	Symbol	Rating	Units
IXDD602D2 (8-Pin DFN)	Thermal Resistance, Junction-to-Ambient	θ_{JA}	35	°C/W
IXD_602PI (8-Pin DIP)			125	
IXD_602SI (8-Pin Power SOIC)			85	
IXD_602SIA (8-Pin SOIC)			120	
IXD_602SI (8-Pin Power SOIC)	Thermal Resistance, Junction-to-Case	θ_{JC}	10	°C/W

2 IXD_602 Performance

2.1 Timing Diagrams

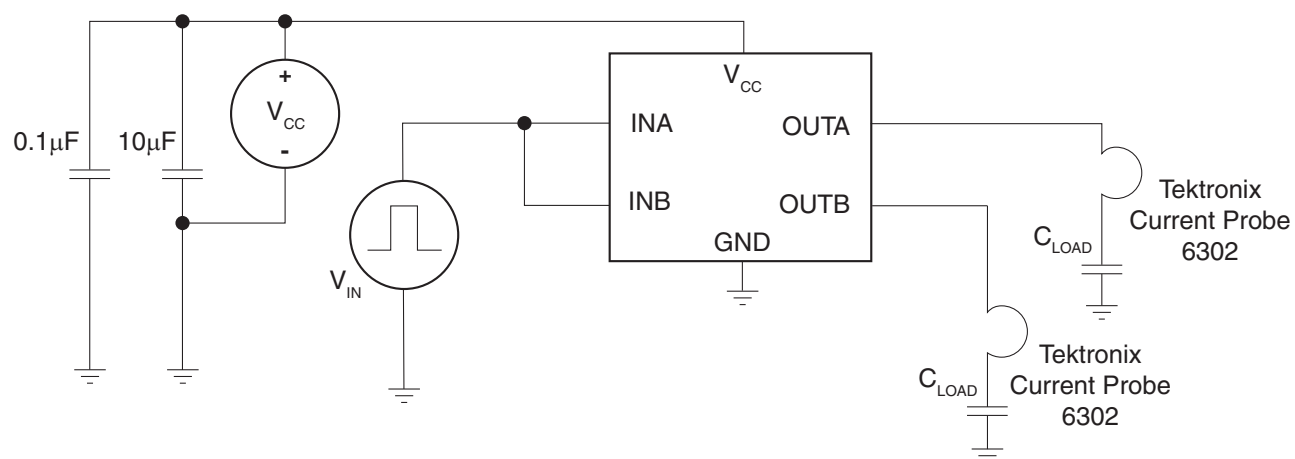


Non-Inverting Driver Waveforms



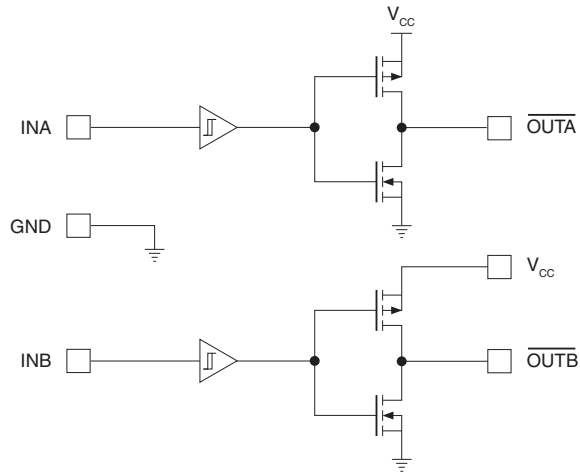
Inverting Driver Waveforms

2.2 Characteristics Test Diagram



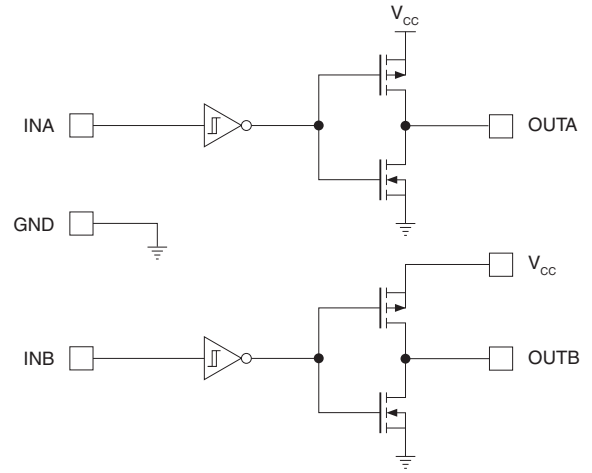
3 Block Diagrams & Truth Tables

3.1 IXDI602



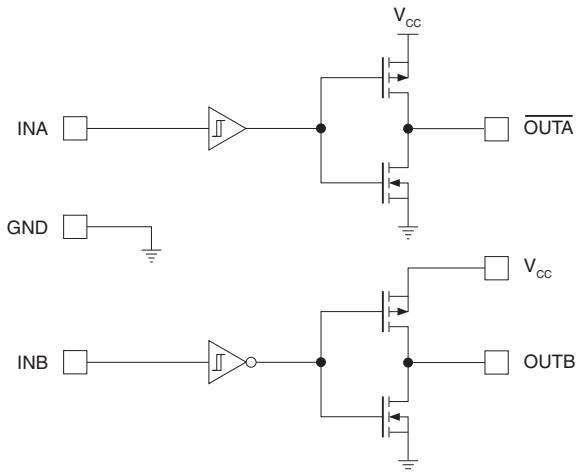
IN_x	$\overline{\text{OUT}}_x$
0	1
1	0

3.3 IXDN602



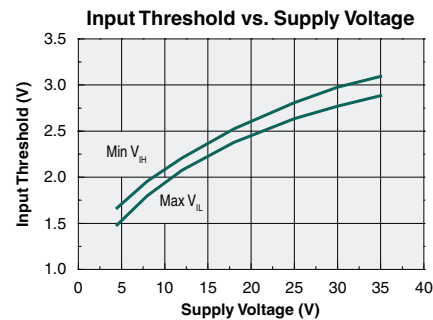
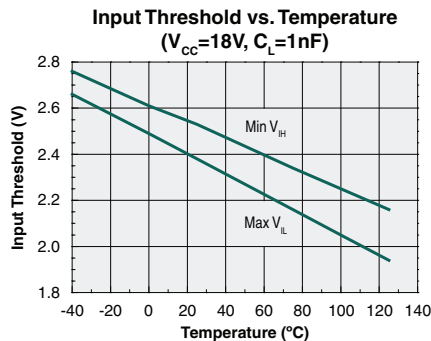
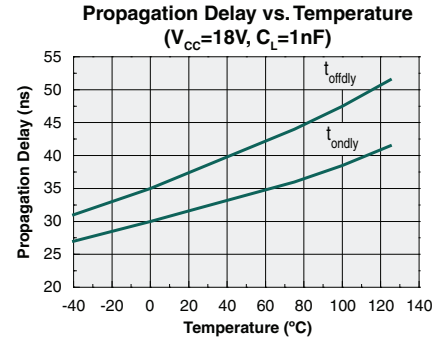
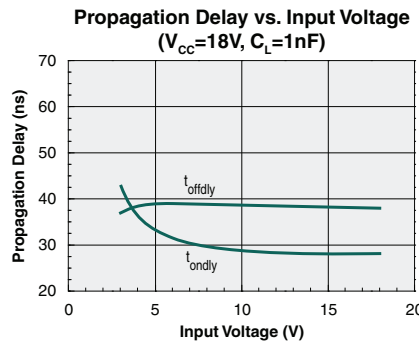
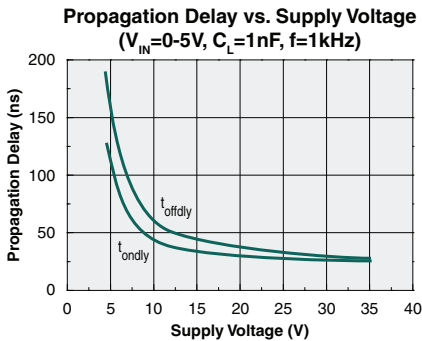
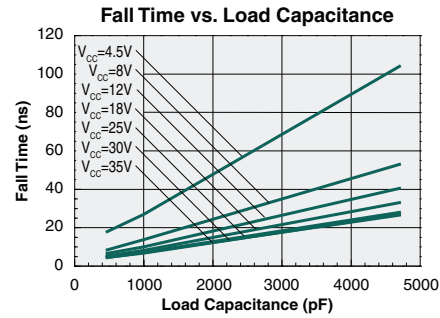
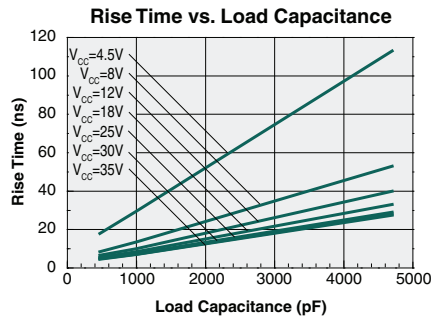
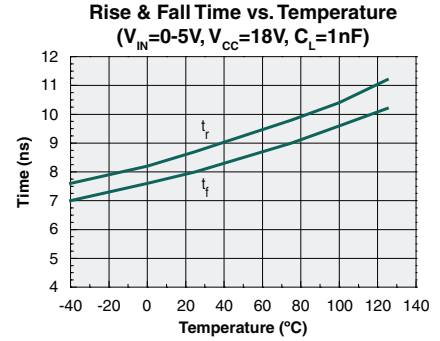
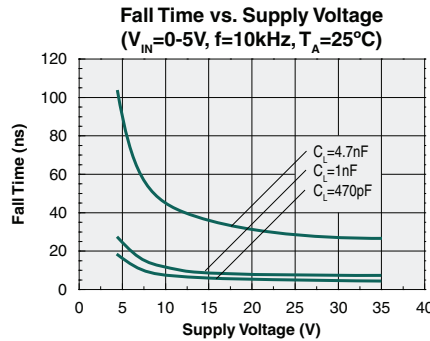
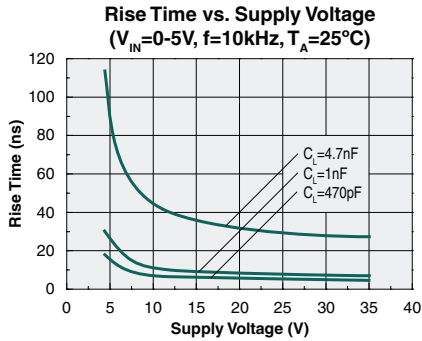
IN_x	OUT_x
0	0
1	1

3.2 IXDF602

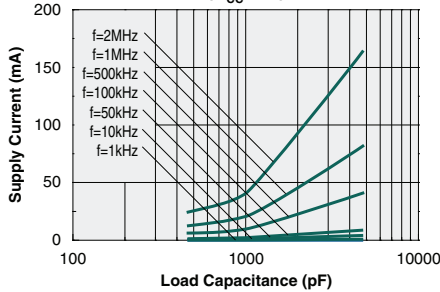


INA	$\overline{\text{OUTA}}$
0	1
1	0
INB	OUTB
0	0
1	1

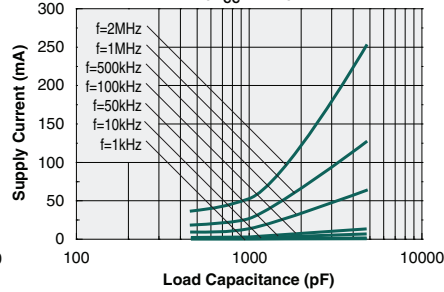
4 Typical Performance Characteristics



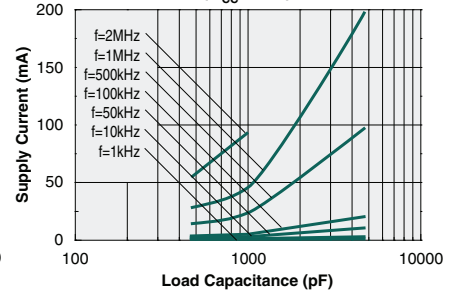
**Supply Current vs. Load Capacitance
Both Outputs Active
($V_{CC}=8V$)**



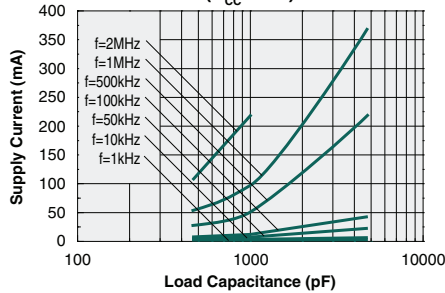
**Supply Current vs. Load Capacitance
Both Outputs Active
($V_{CC}=12V$)**



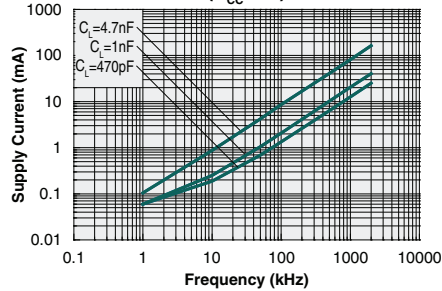
**Supply Current vs. Load Capacitance
Both Outputs Active
($V_{CC}=18V$)**



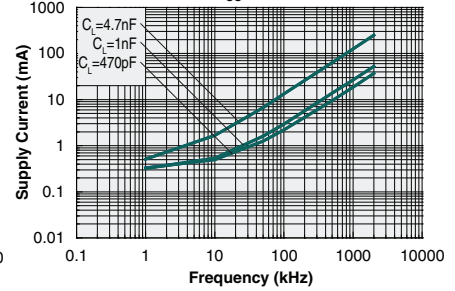
**Supply Current vs. Load Capacitance
Both Outputs Active
($V_{CC}=35V$)**



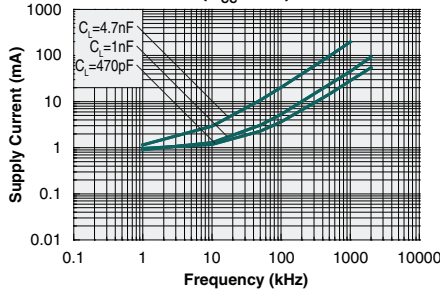
**Supply Current vs. Frequency
Both Outputs Active
($V_{CC}=8V$)**



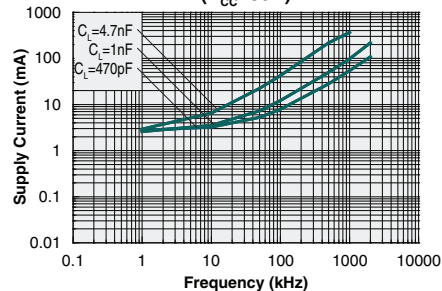
**Supply Current vs. Frequency
Both Outputs Active
($V_{CC}=12V$)**



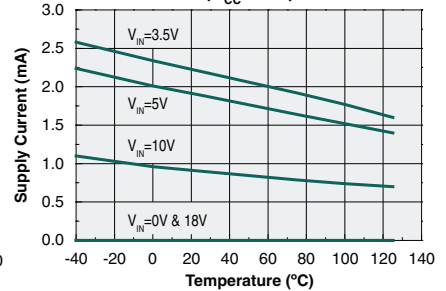
**Supply Current vs. Frequency
Both Outputs Active
($V_{CC}=18V$)**



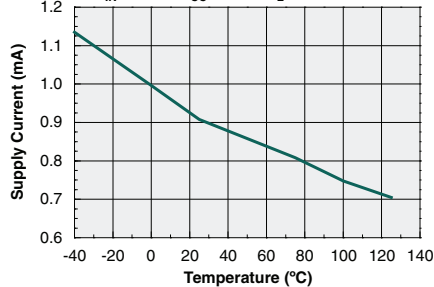
**Supply Current vs. Frequency
Both Outputs Active
($V_{CC}=35V$)**



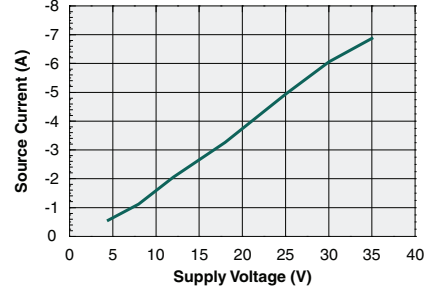
**Quiescent Supply Current
vs. Temperature
($V_{CC}=18V$)**



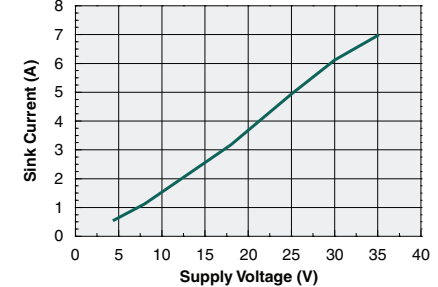
**Dynamic Supply Current
vs. Temperature
($V_{IN}=0-5V$, $V_{CC}=18V$, $C_L=1nF$, $f=1kHz$)**



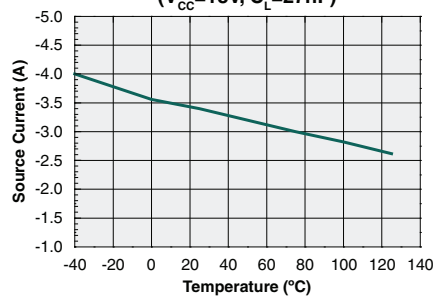
**Output Source Current
vs. Supply Voltage
($C_L=27nF$)**



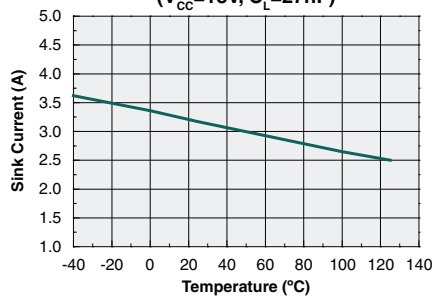
**Output Sink Current
vs. Supply Voltage
($C_L=27nF$)**



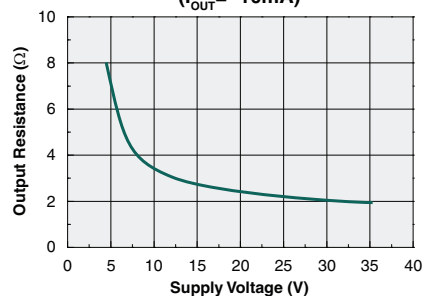
**Output Source Current
vs. Temperature**
($V_{CC}=18V$, $C_L=27nF$)



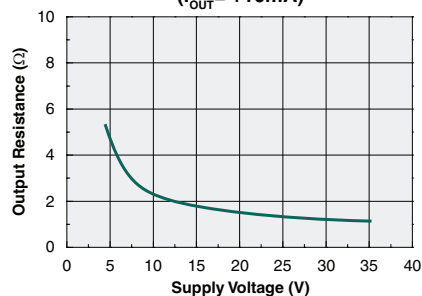
Output Sink Current vs. Temperature
($V_{CC}=18V$, $C_L=27nF$)



**High-State Output Resistance
vs. Supply Voltage**
($I_{OUT} = -10mA$)



**Low State Output Resistance
vs. Supply Voltage**
($I_{OUT} = +10mA$)



5 Manufacturing Information

5.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
IXD_602 All Versions	MSL 1

5.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

5.3 Soldering Profile

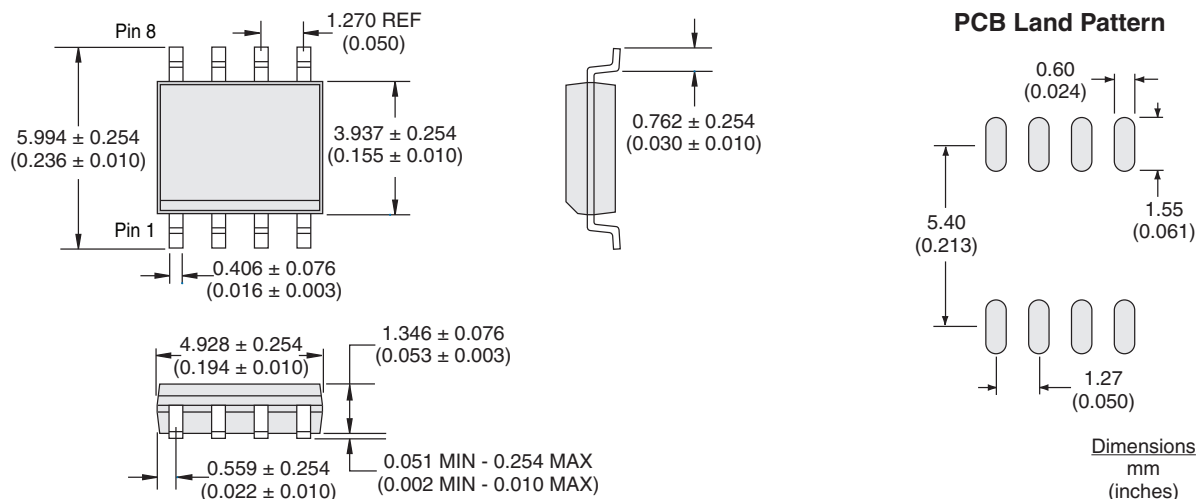
This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time	Maximum Reflow Cycles
IXD_602SI / IXD_602SIA / IXD_602D2	260°C for 30 seconds	3
IXD_602PI	250°C for 30 seconds	-

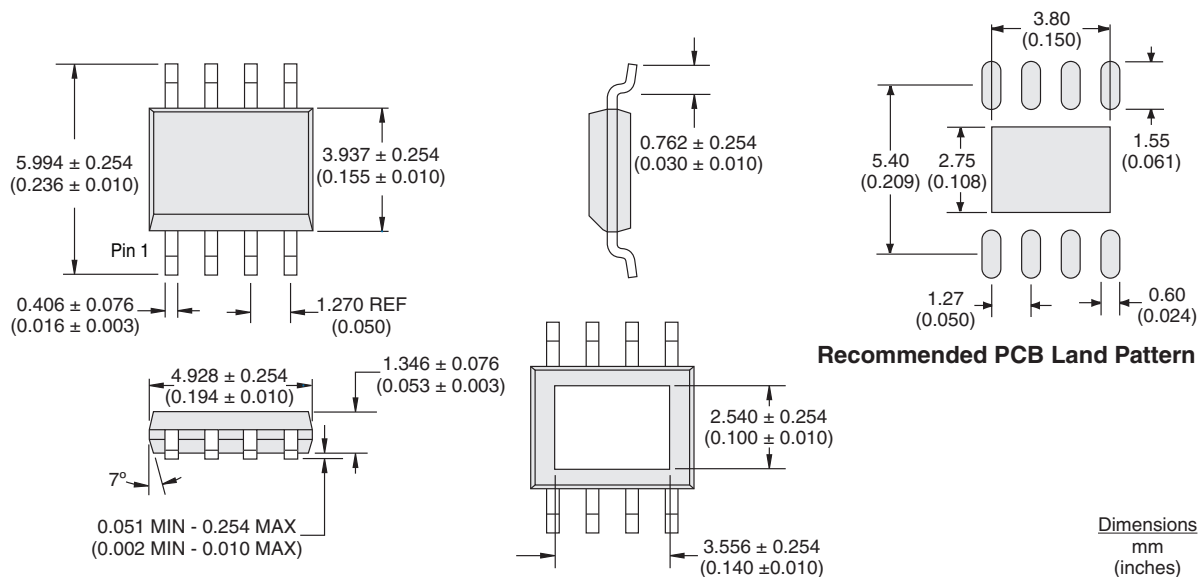


5.4 Mechanical Dimensions

5.4.1 SIA (8-Pin SOIC)



5.4.2 SI (8-Pin Power SOIC with Exposed Metal Back)



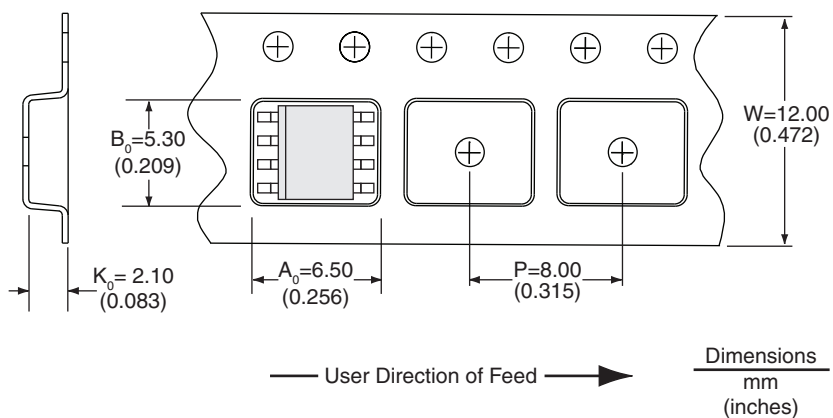
Note: The exposed metal pad on the back of the SI package should be connected to GND. It is not suitable for carrying current.

330.2 DIA.
(13.00 DIA.)

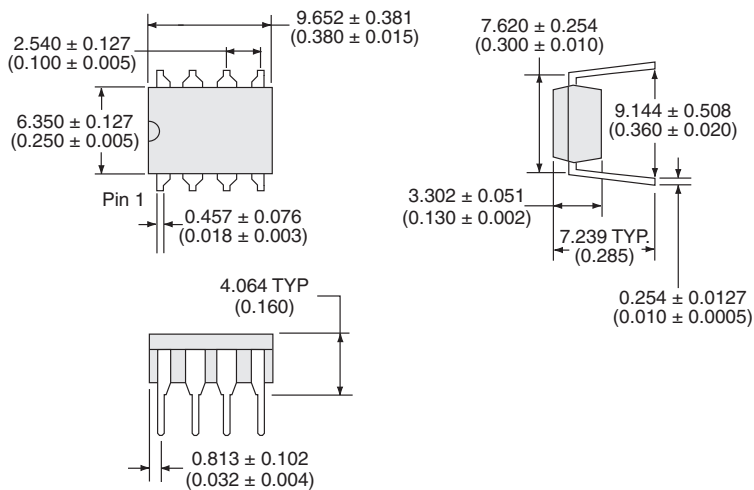
Top Cover
Tape Thickness
0.102 MAX.
(0.004 MAX.)

Embossed Carrier

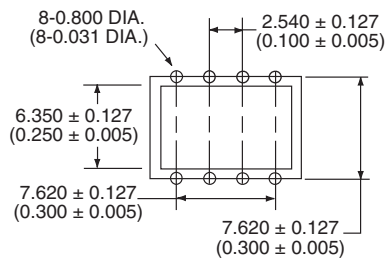
Embossment



5.4.4 PI (8-Pin DIP)

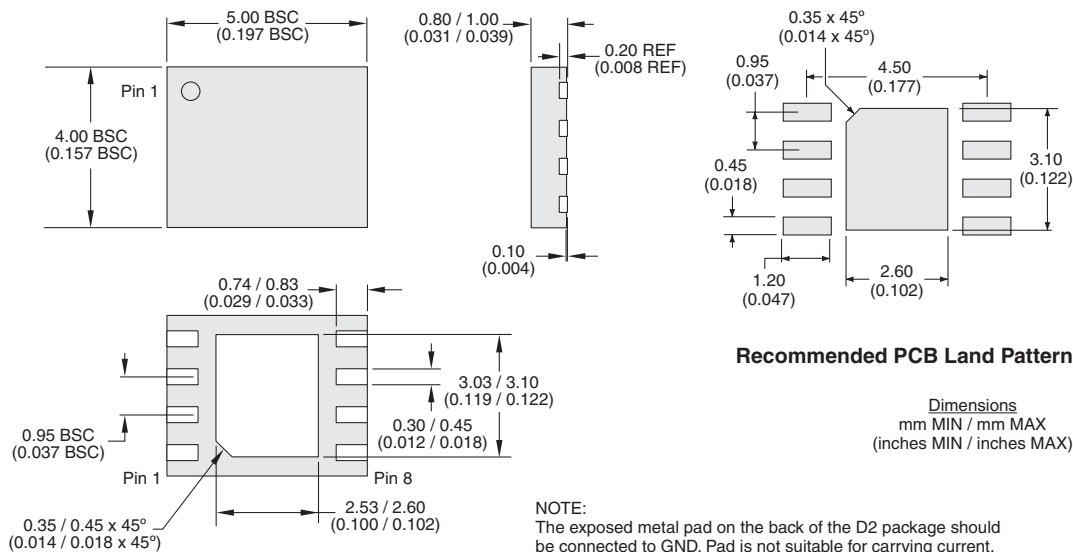


PCB Hole Pattern

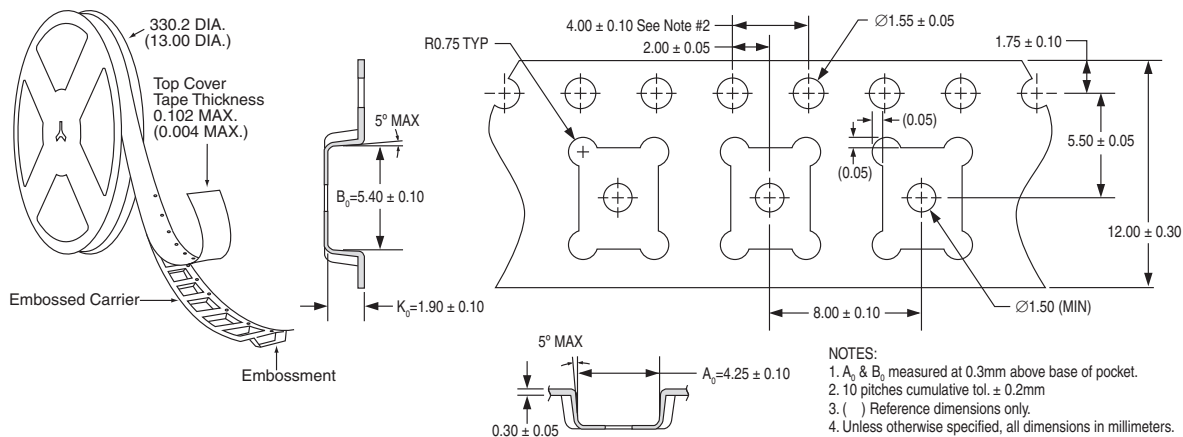


Dimensions
mm
(inches)

5.4.5 D2 (8-Pin DFN)



5.4.6 Tape & Reel Information for D2 Package



For additional information please visit our website at: www.ixysic.com

IXYS Integrated Circuits Division makes no representations or warranties with respect to the accuracy or completeness of the contents of this publication and reserves the right to make changes to specifications and product descriptions at any time without notice. Neither circuit patent licenses nor indemnity are expressed or implied. Except as set forth in IXYS Integrated Circuits Division's Standard Terms and Conditions of Sale, IXYS Integrated Circuits Division assumes no liability whatsoever, and disclaims any express or implied warranty, relating to its products including, but not limited to, the implied warranty of merchantability, fitness for a particular purpose, or infringement of any intellectual property right.

The products described in this document are not designed, intended, authorized or warranted for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or where malfunction of IXYS Integrated Circuits Division's product may result in direct physical harm, injury, or death to a person or severe property or environmental damage. IXYS Integrated Circuits Division reserves the right to discontinue or make changes to its products at any time without notice.

Specification: DS-IXD_602-R06
©Copyright 2014, IXYS Integrated Circuits Division
All rights reserved. Printed in USA.
9/25/2014

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com